

L Number	Hits	Search Text	DB	Time stamp
-	2	("6008128").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 09:09
-	576	(359/223).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 09:09
-	255	(359/298).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 09:09
-	505	(359/838).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 09:13
-	88	(205/116).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 09:14
-	135	((359/223).CCLS.) and silicon\$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 09:20
-	85	((359/298).CCLS.) and silicon\$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 10:21
-	66	((359/838).CCLS.) and silicon\$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 10:30
-	8	((205/116).CCLS.) and silicon\$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 10:33
-	421	silicon and mirror and bulk and monolith\$ and crystal\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 10:43

-	46	(silicon and mirror and bulk and monolith\$ and crystal\$4) and inlet and outlet	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 10:37
-	31	silicon and mirror and bulk and monolith\$ and (crystal\$4 adj plane)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 10:51
-	89	(single adj crystal adj silicon) and mirror and (crystal\$4 adj plane)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 11:08
-	692	(single adj crystal adj silicon) and mirror and plane and etch\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 11:43
-	309	((single adj crystal adj silicon) and mirror and plane and etch\$3) and anisotrop\$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 11:09
-	101	((((single adj crystal adj silicon) and mirror and plane and etch\$3) and anisotrop\$) and fiber and optic\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 11:10
-	121	(single and crystal and silicon) and mirror and plane and etch\$3 and anisotrop\$ and fiber and optic\$4 and internal\$2	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 14:11
-	256	single and crystal\$4 and silicon and mirror and etch\$3 and stripe and intersect\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 14:25
-	118	(single and crystal\$4 and silicon and mirror and etch\$3 and stripe and intersect\$4) and internal	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 11:58
-	373	(single near crystal\$4 near silicon) with mirror	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 12:05

-	39	((single near crystal\$4 near silicon) with mirror) and (fiber n ar optic\$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 12:06
-	3645	digital and mirror and d vice and silicon and crystal\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 14:12
-	168	(digital and mirror and device and silicon and crystal\$4) and bulk and monolith\$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 14:12
-	341	silicon and mirror and etch\$3 and stripe and intersect\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 14:36
-	2259	silicon and mirror and pattern\$3 and anisotrop\$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 14:37
-	403	(single adj crystal\$4 adj silicon) and mirror and pattern\$3 and anisotrop\$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 15:20
-	0	(bulk with (single adj crystal\$4 adj silicon)) and (mirror near pattern\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 15:22
-	20	silicon and (mirror near pattern\$3) and (anisotrop\$ near etch\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 15:34
-	16	silicon and ((mirror near pattern\$3) with array\$)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 15:39
-	2585	(mirror with array\$) and silicon	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 16:16

-	9	(mirror with array\$) and (bulk with single with crystal\$4 with silicon)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 15:43
-	2	((mirror with array\$) and silicon) and anisotrop\$ and (bulk near crystal\$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 15:44
-	2	monolithic adj bulk adj crystal adj silicon	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 16:17
-	2	monolithic with bulk with crystal with silicon	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 16:17
-	1586	monolithic and bulk and crystal and silicon	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 16:18
-	25	(monolithic and bulk and crystal and silicon) and (crystalline near plane)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 16:19
-	362	(monolithic and bulk and crystal and silicon) and (crystalline and plane)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 16:20
-	4	((monolithic and bulk and crystal and silicon) and (crystalline and plane)) and (micro?mirror or (micro adj mirror))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 16:20
-	109	((monolithic and bulk and crystal and silicon) and (crystalline and plane)) and mirror	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 16:41
-	4	silicon near mirror near array	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 16:42

-	1415	digital near (micromirror or micro?mirror or (micro adj mirror)) near d vice	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 16:43
-	350	(digital near (micromirror or micro?mirror or (micro adj mirror)) near device) and silicon	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 17:12
-	16	(digital near (micromirror or micro?mirror or (micro adj mirror)) near device) and (single adj crystal adj silicon)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 17:14
-	3991	(mirror or reflect\$) and (single adj crystal adj silicon)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 17:16
-	240	((mirror or reflect\$) and (single adj crystal adj silicon)) and bulk and monolith\$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 17:42
-	148	anisotrop\$ with silicon with array with etch\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 17:43
-	226	(anisotrop\$ with silicon with process\$) and (mirror or reflector)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 18:38
-	25	silicon and mirror and passage and (crystalline adj plane)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 18:42
-	42	(monolithic and bulk and crystal and silicon) and (mirror or reflector) and crystalline and plane and intersect\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 18:44